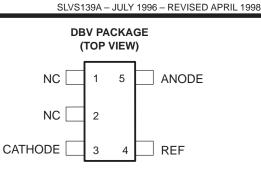
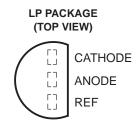
- Low-Voltage Operation . . . Down to 1.24 V
- 1% Reference Voltage Tolerance (TLV431A)
- Adjustable Output Voltage, V<sub>O</sub> = V<sub>ref</sub> to 6 V
- Low Operational Cathode Current . . . 80 μA Typ
- 0.25 Ω Typical Output Impedance
- SOT-23 Package
- Package Options Include Plastic SOT-23 (DBV) and Cylindrical (LP) Packages

#### description

The TLV431 and TLV431A are low-voltage 3-terminal adjustable voltage references with specified thermal stability over applicable industrial and commercial temperature ranges. Output voltage can be set to any value between V<sub>ref</sub> (1.24 V) and 6 V with two external resistors (see Figure 2). The TLV431 and TLV431A operate from a lower voltage (1.24 V) than the widely used TL431 and TL1431 shunt-regulator references.



NC - No internal connection



When used with an optocoupler, the TLV431 and TLV431A are ideal voltage references in isolated feedback circuits for 3-V to 3.3-V switching-mode power supplies. These devices have a typical output impedance of 0.25  $\Omega$ . Active output circuitry provides a very sharp turn-on characteristic, making the TLV431 and TLV431A excellent replacements for low-voltage zener diodes in many applications, including on-board regulation and adjustable power supplies.

The TLV431C and TLV431AC devices are characterized for operation from 0°C to 70°C.

The TLV431I and TLV431AI devices are characterized for operation from -40°C to 85°C.

T.	PACKAGE	CHIP FORM						
TA	TO-92 (LP)	SOT-23 (DBV)	(Y)					
0°C to 70°C	TLV431CLP TLV431ACLP	TLV431CDBV TLV431ACDBV	TLV431Y					
-40°C to 85°C	TLV431ILP TLV431AILP	TLV431IDBV TLV431AIDBV	1204311					

#### AVAILABLE OPTIONS

The LP package is available taped and reeled. Add R suffix to device type (e.g., TLV431ACLPR). The DBV is only available taped and reeled.



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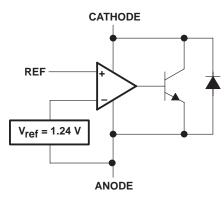
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#### symbol



equivalent schematic

functional block diagram



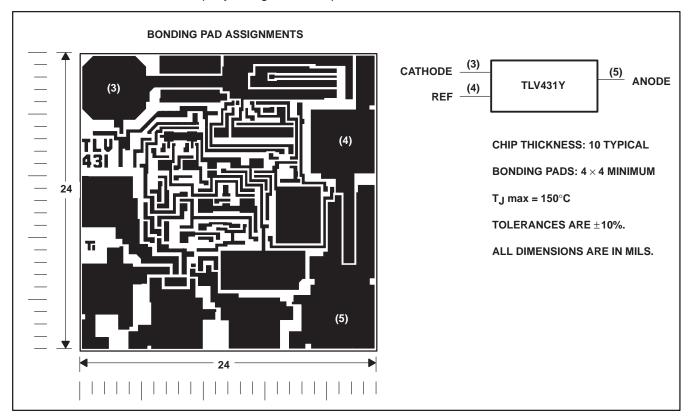
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#### TLV431Y chip information

This chip, when properly assembled, displays characteristics similar to the TLV431 and the TLV431A. Thermal compression or ultrasonic bonding can be used on the doped-aluminum bonding pads. These chips can be mounted with conductive epoxy or a gold-silicon preform.



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Cathode voltage, V <sub>KA</sub> (see Note 1)	
Continuous cathode current range, IK	–20 mA to 20 mA
Reference current range, I <sub>ref</sub>	–0.05 mA to 3 mA
Continuous Total Power dissipation, PD	See Dissipation Rating Table
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Voltage values are with respect to the anode terminal unless otherwise noted.

DISSIPATION RATING TABLE								
PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING				
LP	775 mW	6.2 mW/°C	496 mW	403 mW				
DBV	150 mW	1.2 mW/°C	96 mW	78 mW				



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#### recommended operating conditions

		MIN	MAX	UNIT
Cathode voltage, VKA	Vref	6	V	
Cathode current, IK			15	mA
Operating free-air temperature range, $T_{A}$	TLV431C, TLV431AC	0	70	°C
Operating nee-an temperature range, 1A	TLV431I, TLV431AI	-40	85	C

#### electrical characteristics at 25°C free-air temperature (unless otherwise noted)

PARAMETER		TERTO	ONDITIONS	· · ·	TLV431C		TLV431I			UNIT
	FARAINETER		ONDITIONS	MIN TYP MAX		MIN	TYP	MAX		
			T <sub>A</sub> = 25°C	1.222	1.24	1.258	1.222	1.24	1.258	
V <sub>ref</sub>	Reference voltage	$V_{KA} = V_{ref},$ I <sub>K</sub> = 10 mA	T <sub>A</sub> = full range, (see Note 2 and Figure 1)	1.21		1.27	1.202		1.278	V
V <sub>ref(dev)</sub>	V <sub>ref</sub> deviation over full temperature range (see Note 3)	$V_{KA} = V_{ref}$ , (see Note 2 and	I <sub>K</sub> = 10 mA, Figure 1)		4	12		6	20	mV
$\frac{\Delta V_{ref}}{\Delta V_{KA}}$	Ratio of V <sub>ref</sub> change in cathode voltage change	I <sub>K</sub> = 10 mA, (see Figure 2)	$V_{KA} = V_{ref}$ to 6 V,		-1.5	-2.7		-1.5	-2.7	$\frac{mV}{V}$
I <sub>ref</sub>	Reference terminal current	I <sub>K</sub> = 10 mA, R2 = open,	R1 = 10 k $\Omega$ , (see Figure 2)		0.15	0.5		0.15	0.5	μA
Iref(dev)	I <sub>ref</sub> deviation over full temperature range (see Note 3)	$I_{K} = 10 \text{ mA},$ R2 = open, (see Note 2 and	R1 = 10 kΩ, Figure 2)		0.05	0.3		0.1	0.4	μΑ
I <sub>K(min)</sub>	Minimum cathode current for regulation	$V_{KA} = V_{ref},$	(see Figure 1)		55	80		55	80	μΑ
IK(off)	Off-state cathode current	V <sub>KA</sub> = 6 V, (see Figure 3)	$V_{ref} = 0,$		0.001	0.1		0.001	0.1	μA
z <sub>ka</sub>	Dynamic impedance (see Note 4)	$V_{KA} = V_{ref}$ , $I_K = 0.1 \text{ mA to 1}$ (see Figure 1)	f ≤ 1 kHz, 5 mA		0.25	0.4		0.25	0.4	Ω

NOTES: 2. Full temperature range is -40°C to 85°C for TLV431I, and 0°C to 70°C for the TLV431C.

 The deviation parameters V<sub>ref(dev)</sub> and I<sub>ref(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage, αV<sub>ref</sub>, is defined as:

$$|\alpha V_{ref}| \left(\frac{ppm}{^{\circ}C}\right) = \frac{\left(\frac{V_{ref}(dev)}{V_{ref} (T_A = 25^{\circ}C)}\right) \times 10^{6}}{\Delta T_A}$$

where  $\Delta T_A$  is the rated operating free-air temperature range of the device.

 $\alpha_{Vref}$  can be positive or negative depending on whether minimum V<sub>ref</sub> or maximum V<sub>ref</sub>, respectively, occurs at the lower temperature.

4. The dynamic impedance is defined as: 
$$|z_{ka}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$$

When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by:

$$\left|z_{ka}\right| = \frac{\Delta V}{\Delta I} \approx \left|z_{ka}\right| \times \left(1 + \frac{R1}{R2}\right)$$



	DADAMETED		TEST CONDITIONS		TLV431AC		TLV431AI					
PARAMETER		TESTC			TYP	MAX	MIN	TYP	MAX	UNIT		
			$T_A = 25^{\circ}C$	1.228	1.24	1.252	1.228	1.24	1.252			
V <sub>ref</sub>	Reference voltage	$V_{KA} = V_{ref},$ $I_K = 10 \text{ mA},$	T <sub>A</sub> = full range, (see Note 2 and Figure 1)	1.221		1.259	1.215		1.265	V		
	Vref deviation over full	$V_{KA} = V_{ref}$	I <sub>K</sub> = 10 mA,									mV
Vref(dev)	temperature range (see Note 3)	(see Note 2 and	Figure 1)		4	12		6	20			
$\Delta V_{ref}$	Ratio of V <sub>ref</sub> change in	I <sub>K</sub> = 10 mA,	$V_{KA} = V_{ref}$ to 6 V,	, –1.5	-1.5	-2.7		-1.5	-2.7	mV V		
$\Delta V_{KA}$	cathode voltage change	(see Figure 2)								V		
Iref	Reference terminal current	I <sub>K</sub> = 10 mA,	R1 = 10 kΩ,		0.15	0.5		0.15	0.5	μA		
rei		(see Figure 2)			0.10	0.0		0.10	0.0	μπ		
	I <sub>ref</sub> deviation over full temperature range (see Note 3)	I <sub>K</sub> = 10 mA,	R1 = 10 kΩ,									
Iref(dev)		R2 =open,			0.05	0.3		0.1	0.4	μΑ		
		(see Note 2 and	Figure 2)									
I <sub>K(min)</sub>	Minimum cathode current for regulation	$V_{KA} = V_{ref}$	(see Figure 1)		55	80		55	80	μA		
IK(off)	Off-state cathode current	V <sub>KA</sub> = 6 V, (see Figure 3)	$V_{ref} = 0,$		0.001	0.1		0.001	0.1	μA		
z <sub>ka</sub>		$V_{KA} = V_{ref},$	f ≤ 1 kHz,									
	Dynamic impedance (see Note 4)	$I_{\rm K} = 0.1  \rm{mA}  \rm{to}  1$		0.25 0.4		0.4		0.25	0.4	Ω		
		(see Figure 1)										

#### electrical characteristics at 25°C free-air temperature (unless otherwise noted)

NOTES: 2. Full temperature range is -40°C to 85°C for TLV431AI, and 0°C to 70°C for the TLV431AC.

 The deviation parameters V<sub>ref(dev)</sub> and I<sub>ref(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage, αV<sub>ref</sub>, is defined as:

$$|\alpha V_{ref}| \binom{ppm}{^{\circ}C} = \frac{\left(\frac{V_{ref}(dev)}{V_{ref} (T_A = 25^{\circ}C)}\right) \times 10^{6}}{\Delta T_A}$$

where  $\Delta T_A$  is the rated operating free-air temperature range of the device.

 $\alpha_{Vref}$  can be positive or negative depending on whether minimum V<sub>ref</sub> or maximum V<sub>ref</sub>, respectively, occurs at the lower temperature.

temperature. 4. The dynamic impedance is defined as:  $|z_{ka}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$ 

When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by:

$$\left|z_{ka}\right| = \frac{\Delta V}{\Delta I} \approx \left|z_{ka}\right| \times \left(1 + \frac{R1}{R2}\right)$$



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#### electrical characteristics at 25°C free-air temperature

PARAMETER		TEST	TEST CONDITIONS		TLV431Y		
	PARAMETER	TEST	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference voltage	$V_{KA} = V_{ref},$ $I_K = 10 \text{ mA},$ (see Figure 1)	T <sub>A</sub> = 25°C		1.24		V
$\frac{\Delta V_{ref}}{\Delta V_{KA}}$	Ratio of $V_{\mbox{ref}}$ change in cathode voltage change	I <sub>K</sub> = 10 mA, (see Figure 2)	$\Delta V_{KA} = V_{ref}$ to 6 V,		-1.5		$\frac{mV}{V}$
I <sub>ref</sub>	Reference terminal current	I <sub>K</sub> = 10 mA, R2 = open,	R1 = 10 k $\Omega$ , (see Figure 2)		0.15		μΑ
IK(min)	Minimum cathode current for regulation	$V_{KA} = V_{ref}$	(see Figure 1)		55		μA
loff	Off-state cathode current	V <sub>KA</sub> = 6 V, (see Figure 3)	$V_{ref} = 0,$		0.001		μΑ
z <sub>ka</sub>	Dynamic impedance (see Note 4)	$V_{KA} = V_{ref},$ $I_K = 0.1 \text{ mA to } 1$ (see Figure 1)	f ≤ 1 kHz, 5 mA		0.25		Ω
	41	/		•			·!

NOTE 4: The dynamic impedance is defined as:

$$|z_{ka}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$$

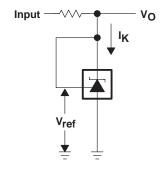
When the device is operating with two external resistors (see Figure 2), the total dynamic impedance of the circuit is given by:

 $\left|z_{ka}\right| \ = \frac{\Delta V}{\Delta I} \approx \ \left|z_{ka}\right| \ \times \left(1 \ + \frac{R1}{R2}\right)$ 



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## PARAMETER MEASUREMENT INFORMATION



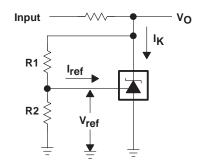


Figure 1. Test Circuit for  $V_{KA} = V_{ref}$ ,  $V_O = V_{KA} = V_{ref}$ 

Figure 2. Test Circuit for V<sub>KA</sub> > V<sub>ref</sub>, V<sub>O</sub> = V<sub>KA</sub> = V<sub>ref</sub> × (1 + R1/R2) + I<sub>ref</sub> × R1

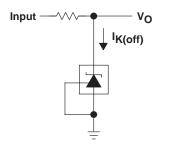
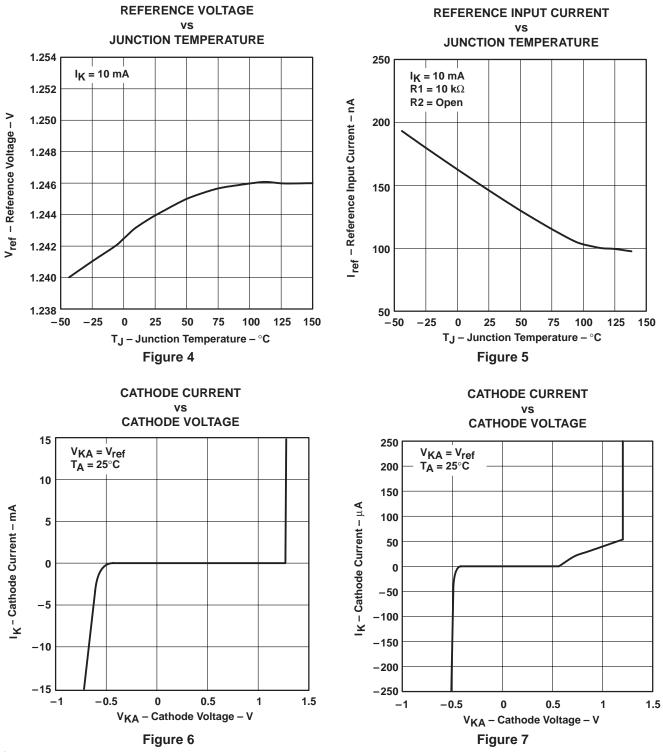


Figure 3. Test Circuit for IK(off)



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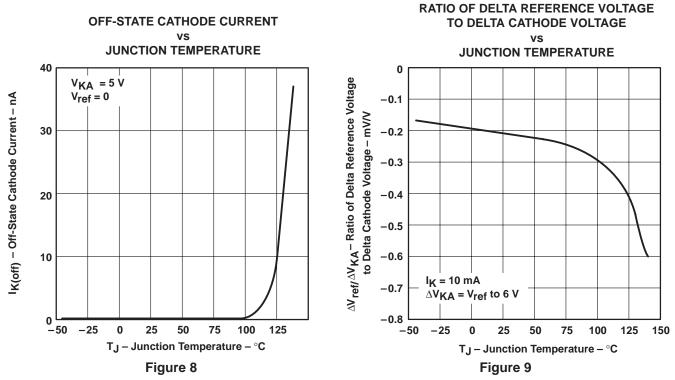


PARAMETER MEASUREMENT INFORMATION<sup>†</sup>

<sup>†</sup> Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.



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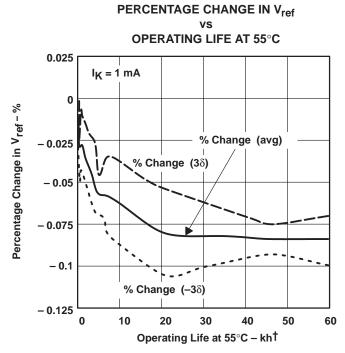


#### PARAMETER MEASUREMENT INFORMATION<sup>†</sup>

<sup>†</sup> Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.



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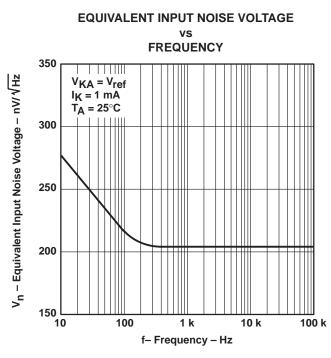


#### PARAMETER MEASUREMENT INFORMATION

<sup>†</sup> Extrapolated from life-test data taken at 125°C; the activation energy assumed is 0.7 eV.

Figure 10





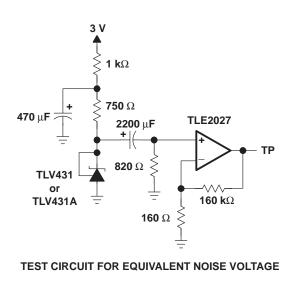
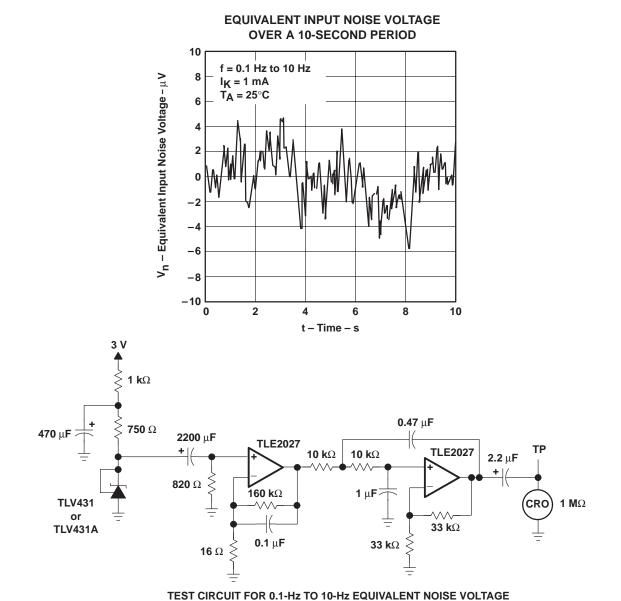


Figure 11

PARAMETER MEASUREMENT INFORMATION



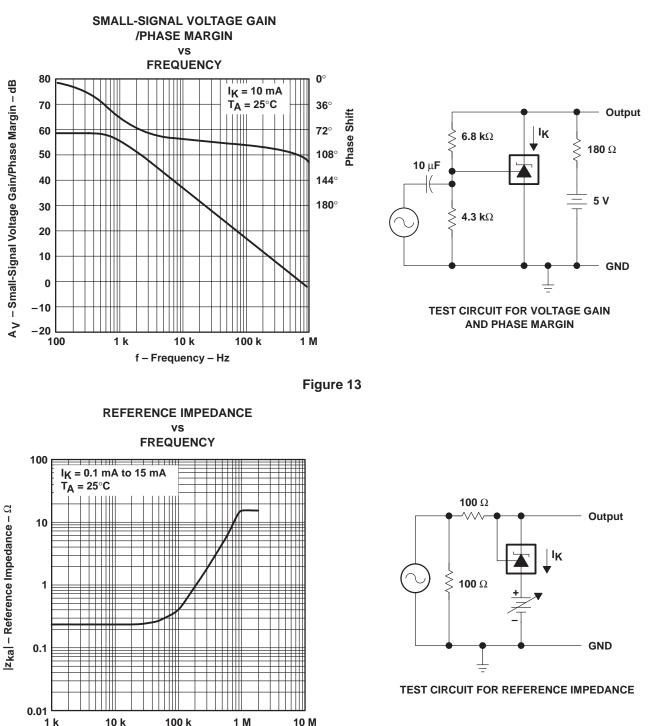
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### PARAMETER MEASUREMENT INFORMATION

Figure 12





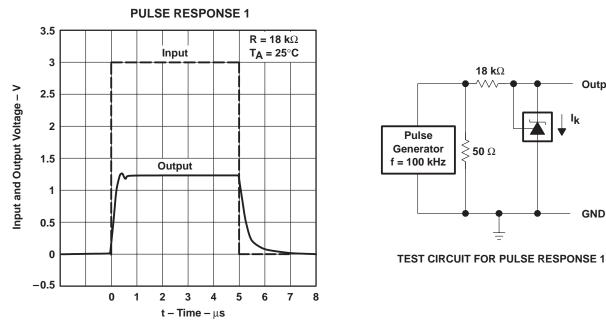
#### PARAMETER MEASUREMENT INFORMATION



f - Frequency - Hz

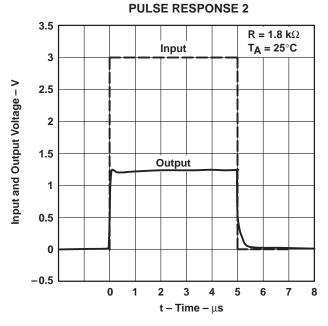


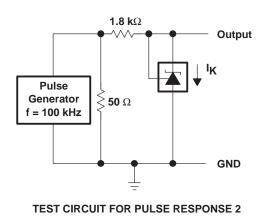
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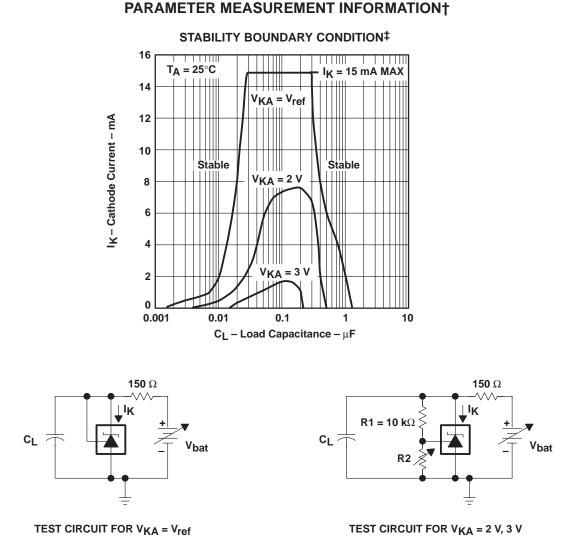


Output

GND





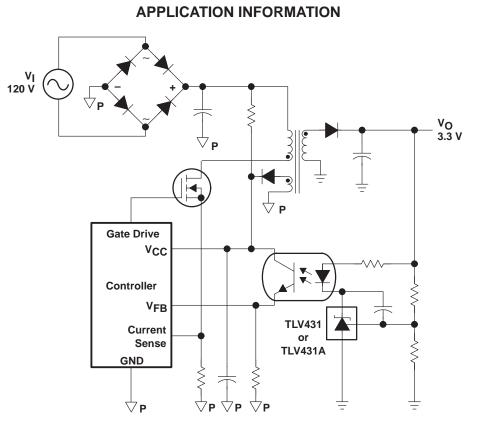


# <sup>†</sup> Operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. <sup>‡</sup> The areas under the curves represent conditions that may cause the device to oscillate. For $V_{KA} = 2 V$ and 3 V curves, R2 and $V_{bat}$ were adjusted to establish the initial $V_{KA}$ and $I_K$ conditions with $C_L = 0$ . $V_{bat}$ and $C_L$ then were adjusted to determine the ranges of stability.

Figure 17



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#### Figure 18. Flyback With Isolation Using TLV431 or TLV431A as Voltage Reference and Error Amplifier

Figure 18 shows the TLV431 or TLV431A used in a 3.3-V isolated flyback supply. Output voltage V<sub>O</sub> can be as low as reference voltage V<sub>ref</sub> (1.24 V  $\pm$  1%). The output of the regulator plus the forward voltage drop of the optocoupler LED (1.24 + 1.4 = 2.64 V) determine the minimum voltage that can be regulated in an isolated supply configuration. Regulated voltage as low as 2.7 Vdc is possible in the above topology.



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